

Address by Guest of Honour Prof. Ashutosh Sharma, Secretary, DST, New Delhi

About the Speaker:

- Ashutosh Sharma is the Secretary to the Government of India since January 2015, heading the Department of Science and Technology (DST), where he helped initiate several new programs.
- Ashutosh received his PhD from the State University of New York at Buffalo (SUNYAB; 1988), his MS from the Pennsylvania State University (1984) and B.Tech. from IIT Kanpur (1982). He has been a professor (1997-), an Institute Chair Professor (2007-) and the Head (2003-05) of Chemical Engineering, and the founding Coordinator of Nanosciences Center and Advanced Imaging Center at the Indian Institute of Technology at Kanpur.
- He has published over 340 peer reviewed papers, filed over 15 patents, given over 150 invited or key note conference presentations and mentored a successful nanotechnology startup.
- Ashutosh is a recipient of numerous honors and awards including the inaugural Infosys Prize in Engineering and Computer Science, TWAS Science Prize of the World Academy of Sciences, Bessel Research Award of the Humboldt Foundation, J. C. Bose Fellowship, Bhatnagar Prize, Homi J. Bhabha Award of UGC, The Syed Husain Zaheer Medal and the Meghnad Saha Medal of INSA, Distinguished Alumni Awards of IIT Kanpur and SUNY Buffalo, Firodia Award and the Life-time Achievement Award of the Indian Science Congress.
- Ashutosh is an elected Fellow of The Indian National Science Academy, The Indian Academy of Sciences, The
 National Academy of Sciences, India and Indian National Academy of Engineering, The World Academy of
 Sciences (TWAS) and the Asia-Pacific Academy of Materials. He has also served on the Councils of the first
 two. He has been an associate editor of ACS Applied Materials and Interfaces, Proceedings of Indian
 National Science Academy and ASME Journal of Micro- and Nano-Manufacturing and has been on the
 editorial boards of several journals: Carbon; ACS Industrial and Engineering Chemistry Research; Current
 Science; Nanomaterials and Energy; Chemical Engineering Science; Journal of Colloid and Interface Science;
 Canadian Journal of Chemical Engineering and Indian Chemical Engineer.

